Unit: mm

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

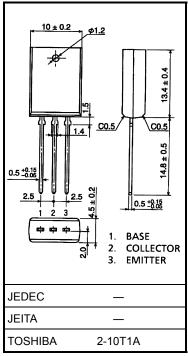
2SA1934

High-Current Switching Applications DC-DC Converter Applications

- Low collector saturation voltage: $V_{CE (sat)} = -0.4 \text{ V (max)} (I_{C} = -3 \text{ A})$
- High-speed switching: $t_{stg} = 1.0 \mu s$ (typ.)
- Complementary to 2SC5176

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	-100	V	
Collector-emitter voltage		V_{CEO}	-80	V	
Emitter-base voltage		V _{EBO}	-7	V	
Collector current	DC	Ic	-5	Α	
	Pulse	I _{CP}	-8		
Base current		ΙΒ	-1	Α	
Collector power dissipation		PC	1.8	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.5 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook

("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

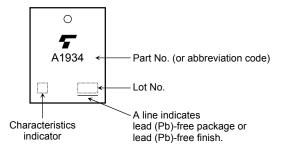


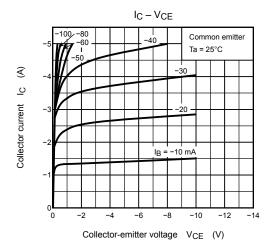
Electrical Characteristics (Ta = 25°C)

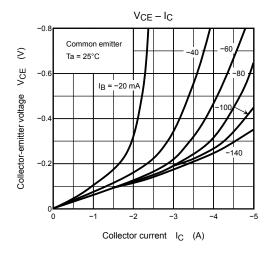
Chara	octeristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I _{CBO}	V _{CB} = -100 V, I _E = 0	_	_	-1	μΑ
Emitter cut-off cur	rent	I _{EBO}	V _{EB} = -7 V, I _C = 0	_	_	-1	μΑ
Collector-emitter	oreakdown voltage	V (BR) CEO	I _C = -10 mA, I _B = 0	-80	_	_	V
DC current gain		h _{FE (1)} (Note)	V _{CE} = -1 V, I _C = -1 A	70	_	240	
		h _{FE (2)}	V _{CE} = -1 V, I _C = -3 A	40	_	_	
Collector-emitter	saturation voltage	V _{CE (sat)}	I _C = -3 A, I _B = -0.15 A	_	-0.2	-0.4	V
Base-emitter satu	ration voltage	V _{BE (sat)}	I _C = -3 A, I _B = -0.15 A	_	-0.9	-1.2	V
Transition frequency		f _T	V _{CE} = -4 V, I _C = -1 A	_	60	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz	_	200	_	pF
Switching time	Turn-on time	t _{on}	Output 20 μ s Input $B2$ $B2$ CC	_	0.2	_	
	Storage time	t _{stg}			1.0	_	μs
	Fall time	t _f		_	0.1	_	

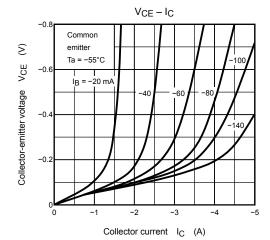
Note: hFE (1) classification O: 70 to 140, Y: 120 to 240

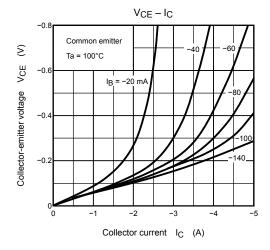
Marking

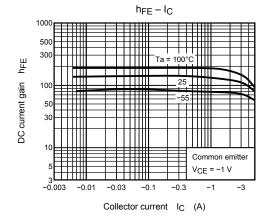


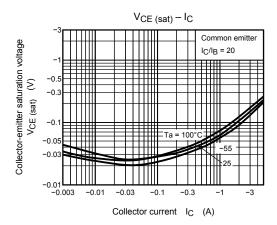




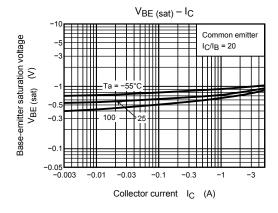


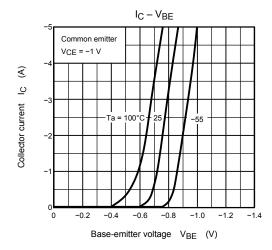


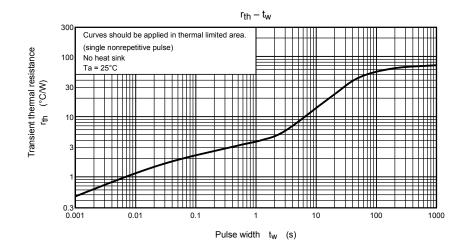


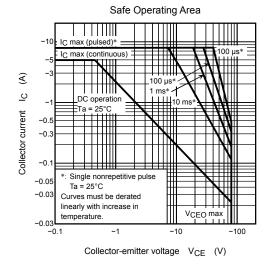


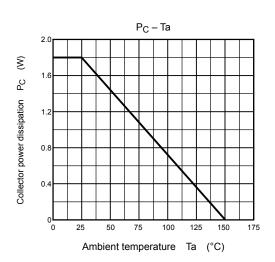
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RESTRICTIONS ON PRODUCT USE

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